BLF573; **BLF573S**

HF / VHF power LDMOS transistor Rev. 4 — 1 September 2015



Product profile

1.1 General description

A 300 W LDMOS RF power transistor for broadcast applications and industrial, scientific and medical applications in the HF to 500 MHz band.

Table 1. **Production test information**

Mode of operation	f	V _{DS}	PL	Gp	η_{D}
	(MHz)	(V)	(W)	(dB)	(%)
CW	225	50	300	27.2	70

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical CW performance at frequency of 225 MHz, a supply voltage of 50 V and an I_{Dq} of 900 mA:
 - ◆ Average output power = 300 W
 - ◆ Power gain = 27.2 dB
 - ◆ Efficiency = 70 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF and VHF band)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

Pinning information 2.

Table 2. **Pinning**

Pin	Description		Simplified outline	Graphic symbol
BLF573 (S	SOT502A)			
1	drain			
2	gate			1
3	source	<u>[1]</u>		2
				3 sym112
BI E5739	(SOT502B)			5,2
1	drain			1
2	gate			نے
3	source	<u>[1]</u>		2
				3
				sym112

^[1] Connected to flange.

Ordering information 3.

Table 3. **Ordering information**

Type number	Packag	kage				
	Name	Description	Version			
BLF573	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A			
BLF573S	-	earless flanged LDMOST ceramic package, 2 leads	SOT502B			

Limiting values

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	110	V
V_{GS}	gate-source voltage		-0.5	+11	V
I_D	drain current		-	42	Α
T_{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	225	°C

Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T _{case} = 80 °C; P _L = 300 W	<u>[1]</u>	0.21	K/W

^[1] $R_{th(j-c)}$ is measured under RF conditions.

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Product data sheet

6. Characteristics

Table 6. DC characteristics

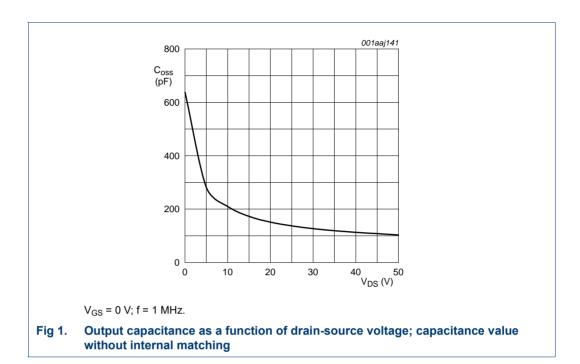
 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 3.75 mA	110	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 375 mA	1.25	1.7	2.25	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_{D} = 900 mA	1.45	1.95	2.45	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	-	4.2	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	44	56	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	420	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 18.75 A	-	20	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 12.49 \text{ A}$	-	0.09	-	Ω
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	2.3	-	pF
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	300	-	pF
C _{oss}	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	103	-	pF

Table 7. RF characteristics

Mode of operation: CW; f = 225 MHz; RF performance at $V_{DS} = 50$ V; $I_{Dq} = 900$ mA; $T_{case} = 25$ °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 300 W	26	27.2	28.4	dB
RLin	input return loss	P _L = 300 W	10	13	-	dB
η_{D}	drain efficiency	P _L = 300 W	67	70	-	%



6.1 Ruggedness in class-AB operation

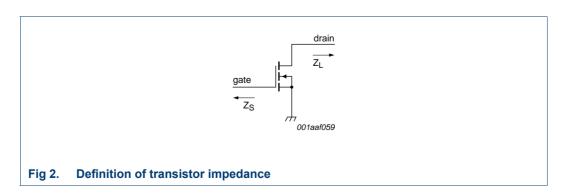
The BLF573 and BLF573S are capable of withstanding a load mismatch corresponding to VSWR = 13 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 900 mA; P_{L} = 300 W; f = 225 MHz.

7. Application information

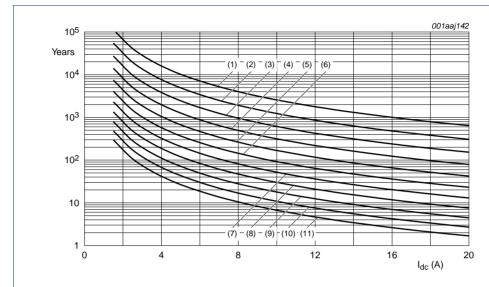
7.1 Impedance information

Table 8. Typical impedance Measured Z_S and Z_L test circuit impedances.

_			
f	Z _S	Z _L	
MHz	Ω	Ω	
225	0.7 + j2.0	1.95 + j2.0	



7.2 Reliability



TTF (0.1 % failure fraction).

- (1) $T_i = 100 \, ^{\circ}C$
- (2) $T_i = 110 \, ^{\circ}C$
- (3) $T_i = 120 \, ^{\circ}C$
- (4) $T_i = 130 \, ^{\circ}C$
- (5) $T_j = 140 \, ^{\circ}C$
- (6) $T_i = 150 \, ^{\circ}C$
- (7) $T_i = 160 \, ^{\circ}C$
- (8) $T_j = 170 \, ^{\circ}C$
- (9) $T_j = 180 \, ^{\circ}\text{C}$
- (10) $T_j = 190 \, ^{\circ}C$
- (11) $T_i = 200 \, ^{\circ}C$

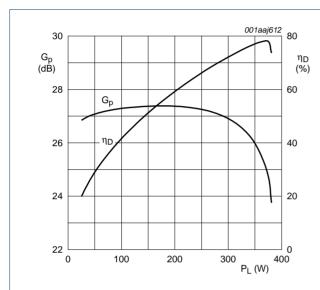
Fig 3. BLF573 and BLF573S electromigration (I_D, total device)

8. Test information

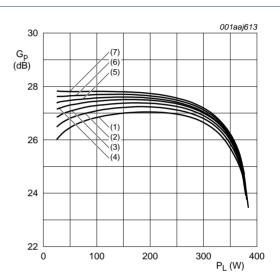
8.1 RF Performance

The following figures are measured in a class-AB production test circuit.

8.1.1 1-Tone CW



 $V_{DS} = 50 \text{ V}; I_{Dq} = 900 \text{ mA}; f = 225 \text{ MHz}.$

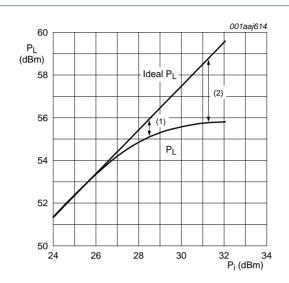


 $V_{DS} = 50 \text{ V; } f = 225 \text{ MHz.}$

- (1) $I_{Dq} = 500 \text{ mA}$
- (2) $I_{Dq} = 700 \text{ mA}$
- (3) $I_{Dq} = 900 \text{ mA}$
- (4) $I_{Dq} = 1100 \text{ mA}$
- (5) $I_{Dq} = 1300 \text{ mA}$
- (6) $I_{Dq} = 1500 \text{ mA}$
- (7) $I_{Dq} = 1700 \text{ mA}$

Fig 4. Power gain and drain efficiency as functions of load power; typical values

Fig 5. Power gain as function of load power; typical values

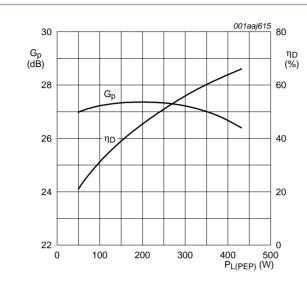


 V_{DS} = 50 V; I_{Dq} = 900 mA; f = 225 MHz.

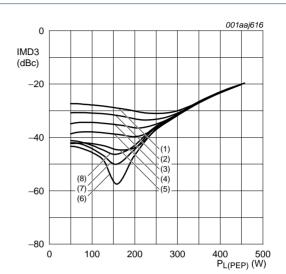
- (1) $P_{L(1dB)} = 55.2 \text{ dBm } (330 \text{ W})$
- (2) $P_{L(3dB)} = 55.8 \text{ dBm } (380 \text{ W})$

Fig 6. Load power as function of input power; typical values

8.1.2 2-Tone CW



 $V_{DS} = 50 \text{ V}; I_{Dq} = 900 \text{ mA}; f_1 = 224.95 \text{ MHz}; f_2 = 225.05 \text{ MHz}.$



 $V_{DS} = 50 \text{ V}$; $f_1 = 224.95 \text{ MHz}$; $f_2 = 225.05 \text{ MHz}$.

- (1) $I_{Dq} = 500 \text{ mA}$
- (2) $I_{Dq} = 700 \text{ mA}$
- (3) $I_{Dq} = 900 \text{ mA}$
- (4) $I_{Dq} = 1100 \text{ mA}$
- (5) $I_{Dq} = 1300 \text{ mA}$
- (6) $I_{Dq} = 1500 \text{ mA}$
- (7) $I_{Dq} = 1700 \text{ mA}$
- (8) $I_{Dq} = 1800 \text{ mA}$

Fig 7. Power gain and drain efficiency as functions of peak envelope load power; typical values

Fig 8. Third order intermodulation distortion as a function of peak envelope load power; typical values

8.2 Test circuit

Table 9. List of components

For production test circuit, see Figure 9 and Figure 10.

Printed-Circuit Board (PCB): Rogers 5880; $\varepsilon_r = 2.2$ F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.

Component	Description	Value	Remarks
B1	ferrite SMD bead	100 Ω; 100 MHz	Ferroxcube BDS3/3/8.9-4S2 or equivalent
C1, C18	multilayer ceramic chip capacitor	100 pF	<u>[1]</u>
C2	multilayer ceramic chip capacitor	39 pF	<u>[1]</u>
C3, C4	multilayer ceramic chip capacitor	180 pF	<u>[1]</u>
C5, C6, C7	multilayer ceramic chip capacitor	220 pF	<u>[1]</u>
C8, C20	multilayer ceramic chip capacitor	1 nF	<u>[1]</u>
C9	multilayer ceramic chip capacitor	4.7 μF	TDK C4532X7R1E475MT020U or equivalent
C10	multilayer ceramic chip capacitor	30 pF	<u>[1]</u>
C11, C12, C13	multilayer ceramic chip capacitor	51 pF	<u>[1]</u>
C14	multilayer ceramic chip capacitor	43 pF	<u>[1]</u>

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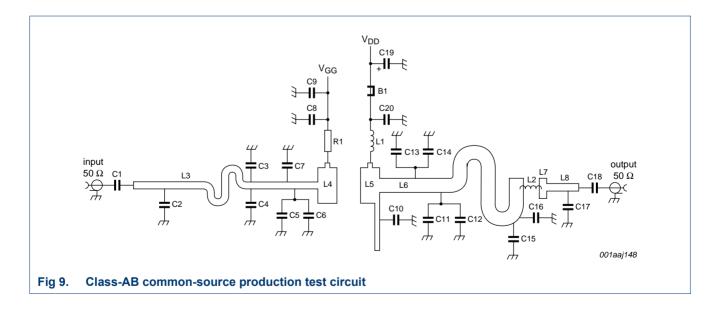
Table 9. List of components ... continued

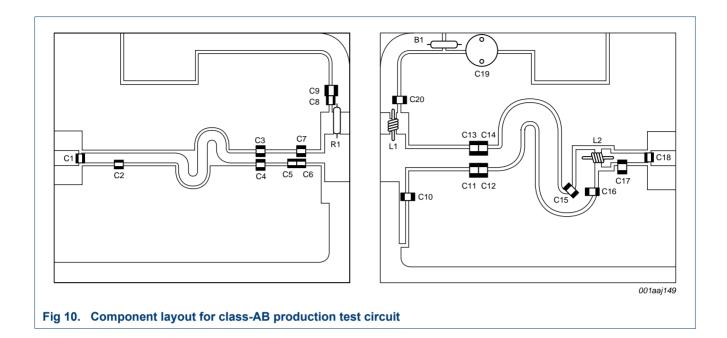
For production test circuit, see Figure 9 and Figure 10.

Printed-Circuit Board (PCB): Rogers 5880; $\varepsilon_r = 2.2$ F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.

Component	Description	Value	Remarks
C15	multilayer ceramic chip capacitor	33 pF	Ш
C16	multilayer ceramic chip capacitor	36 pF	Ш
C17	multilayer ceramic chip capacitor	16 pF	Ш
C19	electrolytic capacitor	220 μF; 63 V	
L1	2 turns enamelled copper wire	D = 3 mm; d = 1 mm; length = 2 mm; leads = 2 × 6 mm	
L2	4 turns enamelled copper wire	D = 2 mm; d = 1 mm; length = 13 mm; leads = 2 × 5 mm	
L3	stripline	-	(L \times W) 96 mm \times 3 mm
L4, L5	stripline	-	(L \times W) 15 mm \times 8 mm
L6	stripline	-	(L \times W) 105 mm \times 6 mm
L7	stripline	-	(L \times W) 3 mm \times 6 mm
L8	stripline	-	(L \times W) 12 mm \times 6 mm
R1	metal film resistor	100 Ω; 0.6 W	

[1] American Technical Ceramics type 100B or capacitor of same quality.





9. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

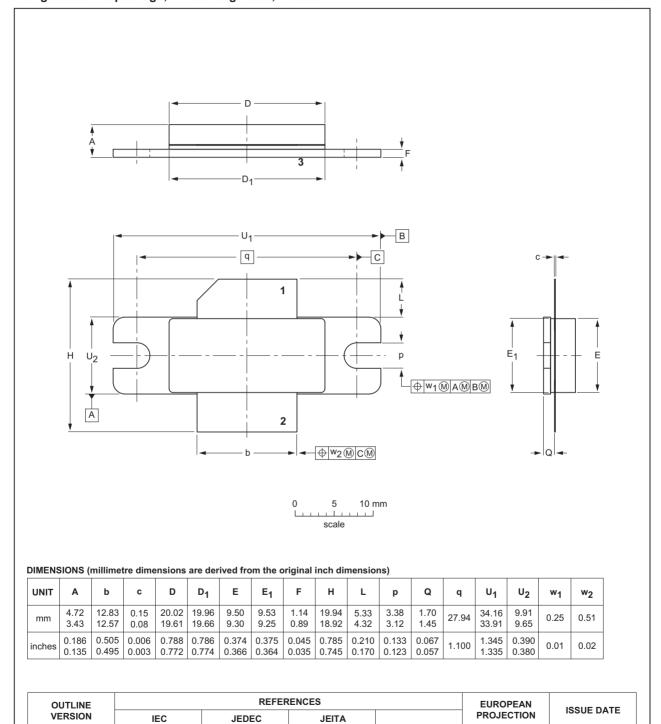


Fig 11. Package outline SOT502A

SOT502A

 \bigcirc

03-01-10

12-05-02

Earless flanged ceramic package; 2 leads

SOT502B

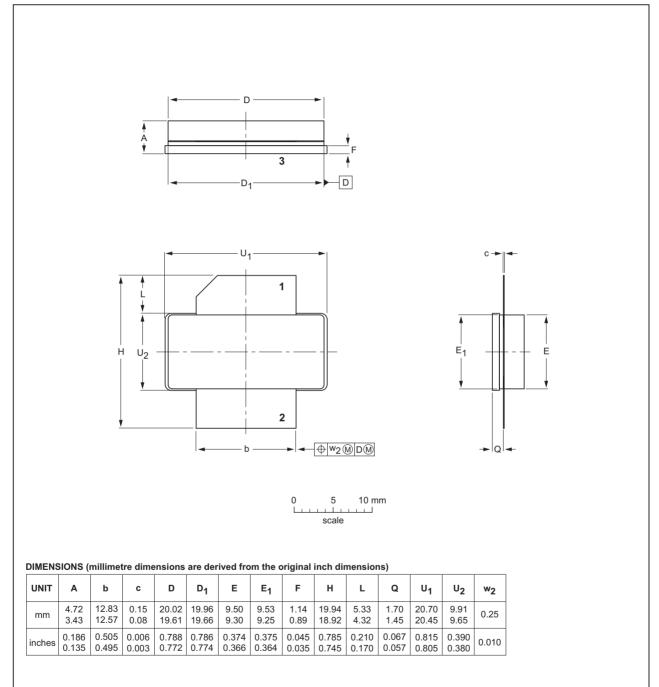


Fig 12. Package outline SOT502B

IEC

OUTLINE

VERSION

SOT502B

JEITA

REFERENCES

JEDEC

ISSUE DATE

07-05-09

12-05-02

EUROPEAN

PROJECTION

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CW	Continuous Wave
EDGE	Enhanced Data rates for GSM Evolution
GSM	Global System for Mobile communications
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
RF	Radio Frequency
SMD	Surface Mount Device
TTF	Time To Failure
VHF	Very High Frequency
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF573_BLF573S#4	20150901	Product data sheet	-	BLF573_BLF573S v.3	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
BLF573_BLF573S v.3	20100708	Product data sheet	-	BLF573S v.2	
BLF573S v.2	20090217	Product data sheet	-	BLF573S v.1	
BLF573S v.1	20081208	Preliminary data sheet	-	-	

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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